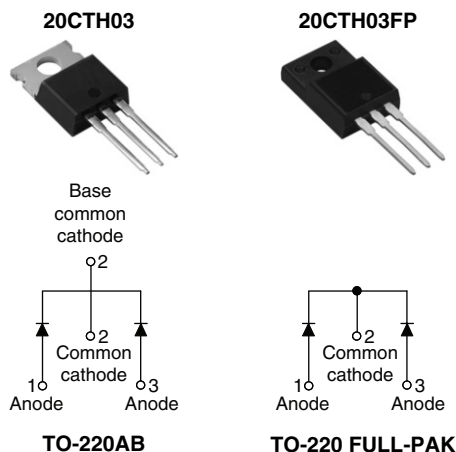


Hyperfast Rectifier, 2 x 10 A FRED P_t[™]



FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Fully isolated package ($V_{INS} = 2500 V_{RMS}$)
- TO-220 designed and qualified for AEC Q101 level
- TO-220FP designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRODUCT SUMMARY

t_{rr} (maximum)	35 ns
$I_{F(AV)}$	2 x 10 A
V_R	300 V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		300	V
Average rectified forward current	$I_{F(AV)}$	per diode	10	A
		(FULL-PAK) per diode		
		per device	20	
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$	120	
Operating junction and storage temperatures	T_J, T_{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	300	-	-	V
Forward voltage	V_F	$I_F = 10\text{ A}$	-	1.05	1.25	
		$I_F = 10\text{ A}, T_J = 125\text{ °C}$	-	0.85	0.95	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	20	μA
		$T_J = 125\text{ °C}, V_R = V_R$ rated	-	6	200	
Junction capacitance	C_T	$V_R = 300\text{ V}$	-	30	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1\text{ A}$, $dI_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	-	35	ns
		$I_F = 1\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	-	30	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	31	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	42	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	2.4	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	5.6	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	36	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	120	-	

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C
Thermal resistance, _____ per diode junction to case (FULL-PAK) per diode	R _{thJC}	Mounting surface, flat, smooth and greased	-	-	1.5	°C/W
			-	-	3.9	
Marking device		Case style TO-220AB	20CTH03			
		Case style TO-220 FULL-PAK	20CTH03FP			

Hyperfast Rectifier, 2 x 10 A FRED Pt™

Vishay High Power Products

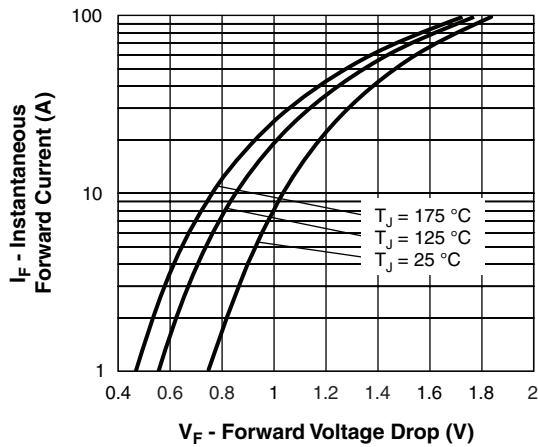


Fig. 1 - Typical Forward Voltage Drop Characteristics

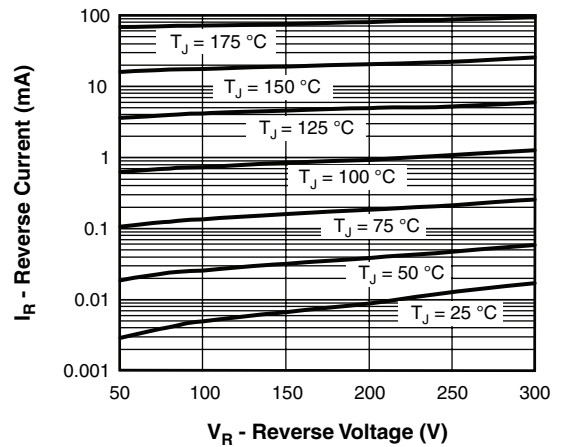


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

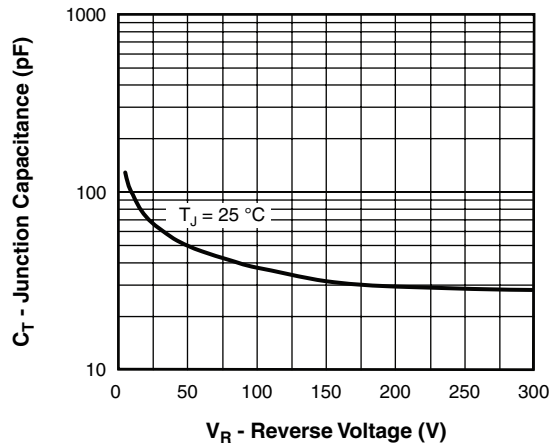


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

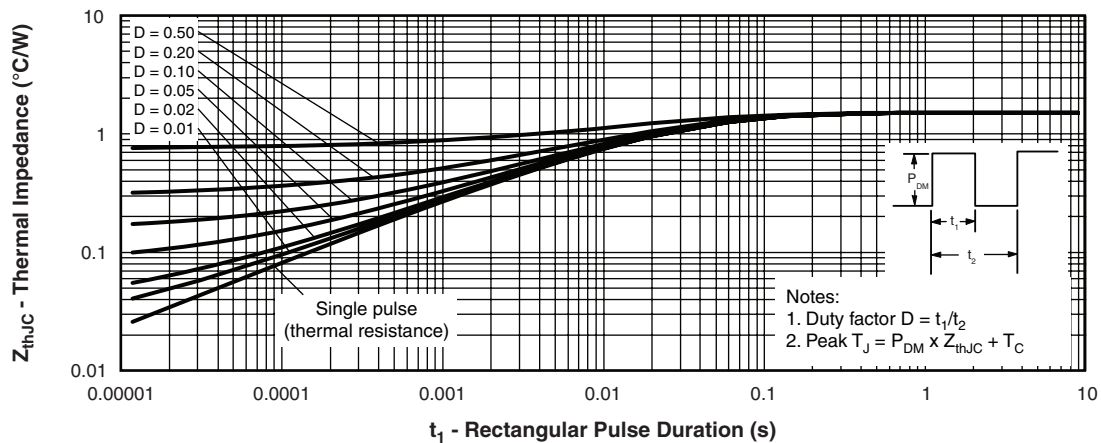


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

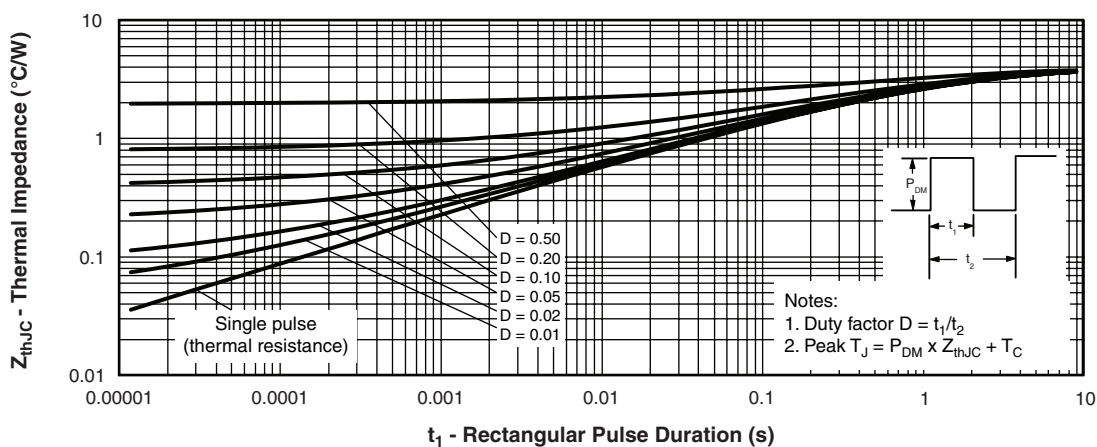
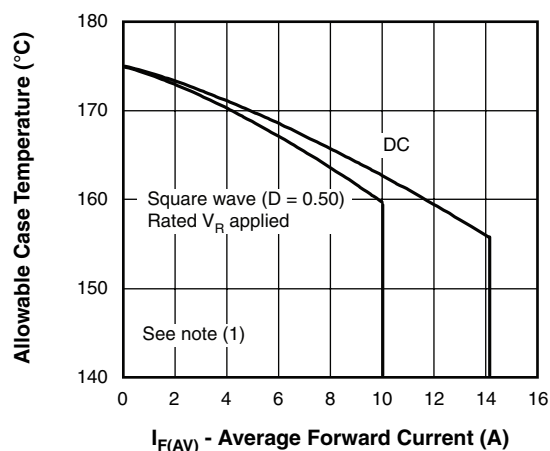
Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

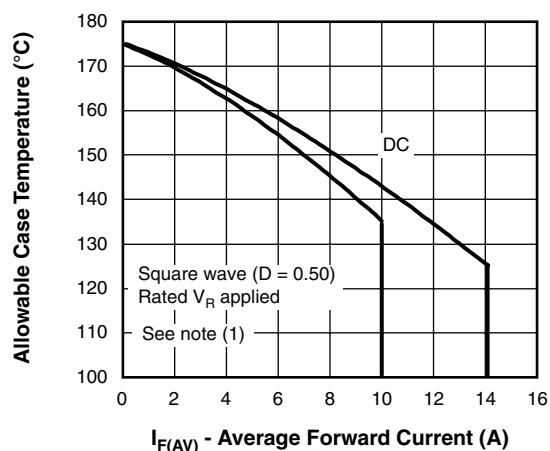


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

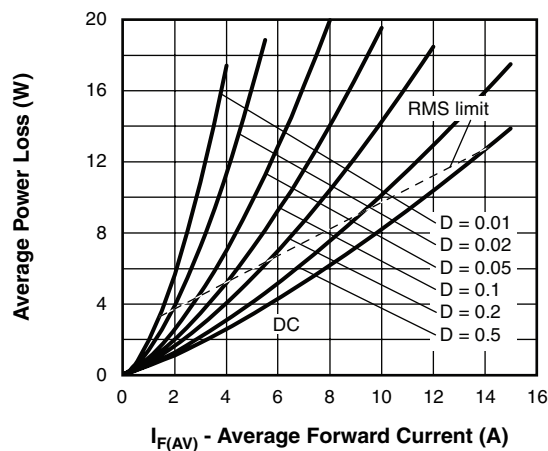


Fig. 8 - Forward Power Loss Characteristics

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 8);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

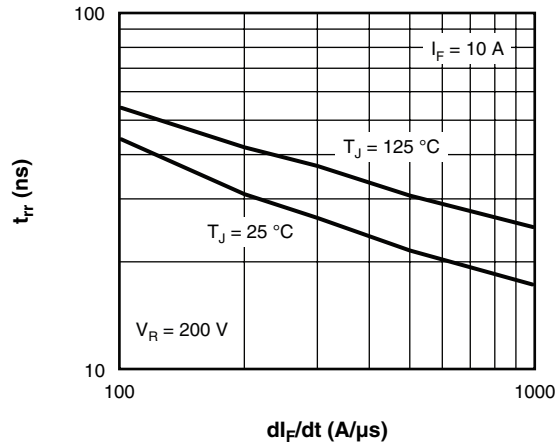
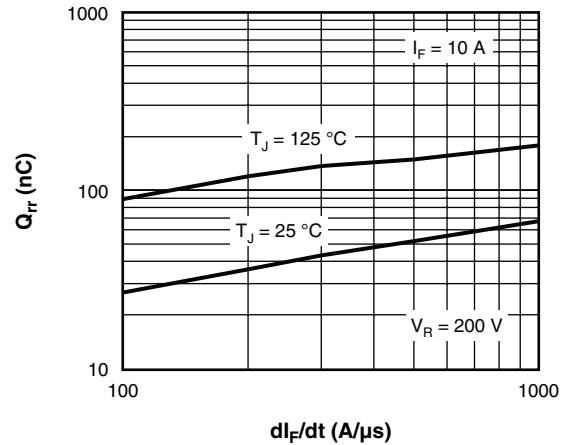
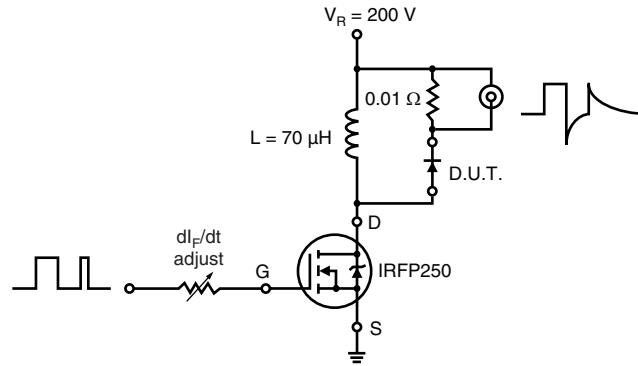

Fig. 9 - Typical Reverse Recovery Time vs. dI_F/dt

Fig. 10 - Typical Stored Charge vs. dI_F/dt


Fig. 11 - Reverse Recovery Parameter Test Circuit

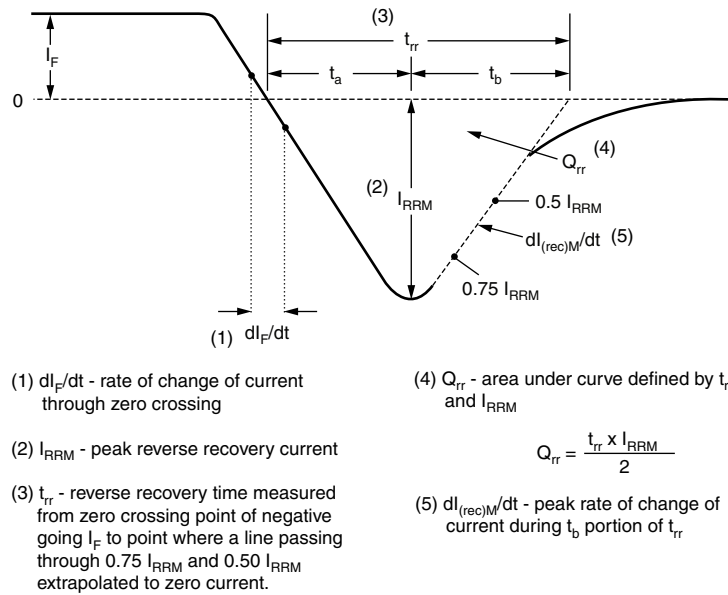


Fig. 12 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	20	C	T	H	03	FP	-
	①	②	③	④	⑤	⑥	⑦

- | | | |
|----------|---|--|
| 1 | - | Current rating (20 = 20 A) |
| 2 | - | C = Common cathode |
| 3 | - | T = TO-220, D ² PAK |
| 4 | - | H = Hyperfast recovery |
| 5 | - | Voltage rating (03 = 300 V) |
| 6 | - | <ul style="list-style-type: none"> • None = TO-220AB • FP = TO-220 FULL-PAK |
| 7 | - | <ul style="list-style-type: none"> • None = Standard production • PbF = Lead (Pb)-free |

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95040
Part marking information	http://www.vishay.com/doc?95042



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